

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters

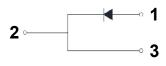


Part Number	Package	Qty(PCS)
HIDH10G120C5	TO-220C-2L	50

Maximum Ratings (Tc=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V		
V _{RSM}	Surge Peak Reverse Voltage	1300	V		
V _R	DC Peak Reverse Voltage	1200	V		
I _F	Continuous Forward Current	33 16 10	А	T _c =25°C T _c =135°C T _c =156°C	Fig. 3
I _{FRM}	Repetitive Peak Forward Surge Current	47 31.5	А	T _c =25°C, t _p =10 ms, Half Sine Pulse T _c =110°C, t _p =10 ms, Half Sine Pulse	
I _{FSM}	Non-Repetitive Forward Surge Current	71 59.5	А	T_c =25°C, t _p =10 ms, Half Sine Pulse T_c =110°C, t _p =10 ms, Half Sine Pulse	Fig. 8
I _{F,Max}	Non-Repetitive Peak Forward Current	750 620	А	T _c =25°C, t _p =10 ms, Pulse T _c =110°C, t _p =10 ms, Pulse	Fig. 8
P _{tot}	Power Dissipation	166.5 72	w	T _c =25°C T _c =110°C	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	V _R =0-960V	
∫i²dt	i²t value	25 17.5	A²s	T _c =25°C, t _p =10 ms T _c =110°C, t _p =10 ms	
TJ	Operating Junction Range	-55 to +175	°C		
T _{stg}	Storage Temperature Range	-55 to +135	°C		
	TO-220 Mounting Torque	1 8.8	Nm Ibf-in	M3 Screw 6-32 Screw	







Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.5 2.2	1.8 3	V	I _F = 10 A T _J =25°C I _F = 10 A T _J =175°C	Fig. 1
I _R	Reverse Current	30 55	250 350	μA	V _R = 1200 V T _J =25°C V _R = 1200 V T _J =175°C	Fig. 2
Q _c	Total Capacitive Charge	52		nC	V _R = 800 V, I _F = 10A di/dt = 200 A/μs T _J = 25°C	Fig. 5
с	Total Capacitance	754 45 38		pF	V _R = 0 V, T _J = 25°C, f = 1 MHz V _R = 400 V, T _J = 25°C, f = 1 MHz V _R = 800 V, T _J = 25°C, f = 1 MHz	Fig. 6
E _c	Capacitance Stored Energy	14.5		μJ	V _R = 800 V	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Тур.	Unit	Note
R _{ejc}	R _{eJC} Thermal Resistance from Junction to Case		°C/W	Fig. 9

Typical Performance

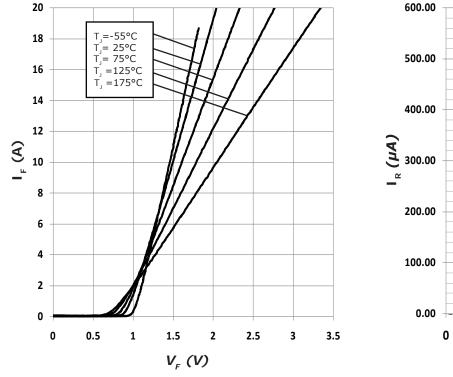


Figure 1. Forward Characteristics

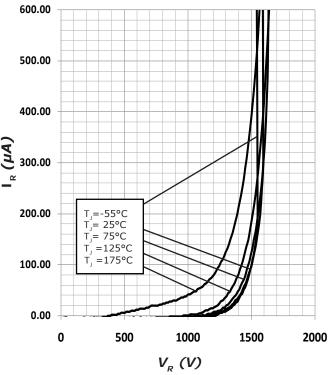


Figure 2. Reverse Characteristics



Typical Performance

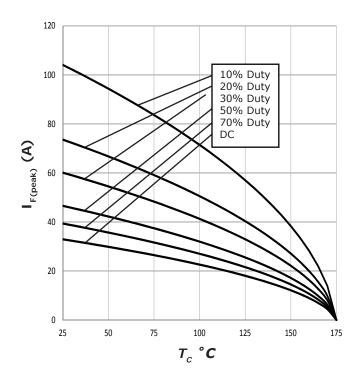


Figure 3. Current Derating

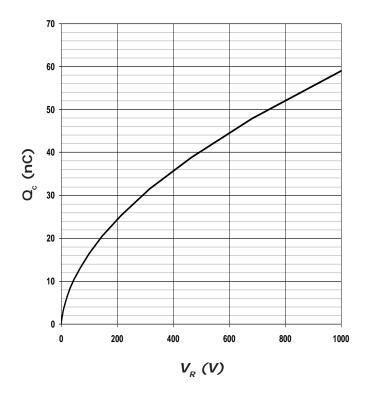


Figure 5. Recovery Charge vs. Reverse Voltage

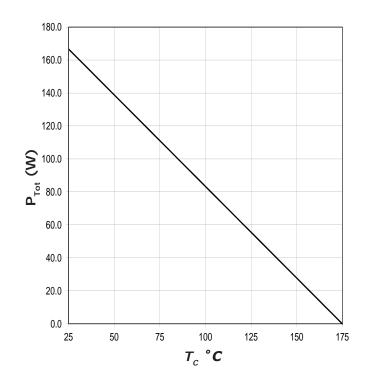


Figure 4. Power Derating

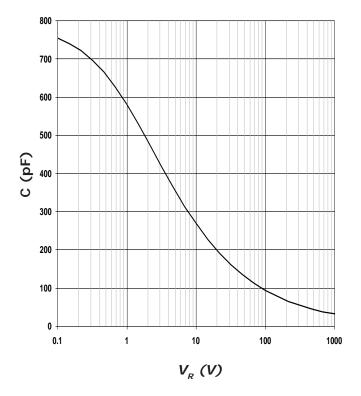


Figure 6. Capacitance vs. Reverse Voltage



Typical Performance

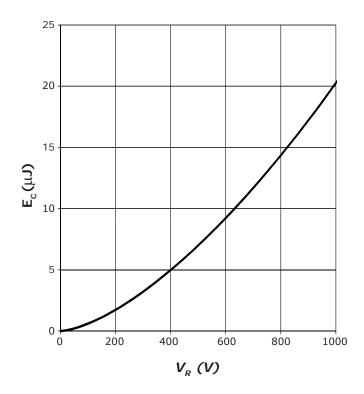


Figure 7. Typical Capacitance Stored Energy

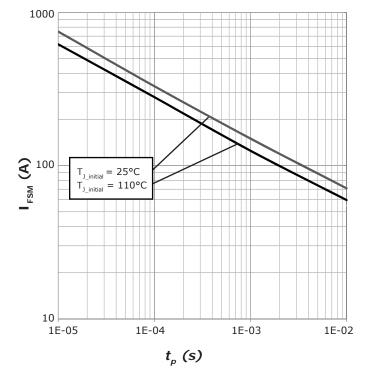


Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

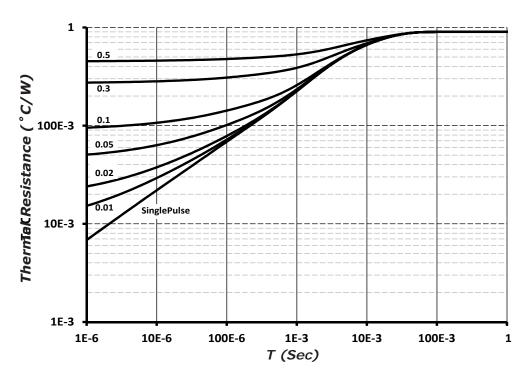
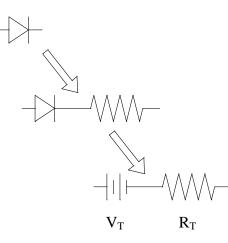


Figure 9. Transient Thermal Impedance



Diode Model

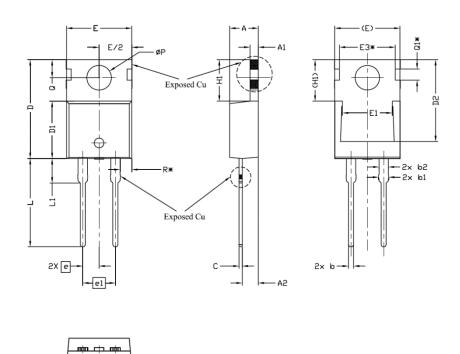


$$V_{TT} = V_{T} + If^{*}R_{T}$$
$$V_{T} = 0.98 + (T_{J}^{*} - 1.71^{*}10^{-3})$$
$$R_{T} = 0.040 + (T_{J}^{*} 5.32^{*}10^{-4})$$

Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

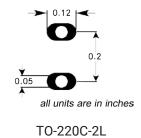


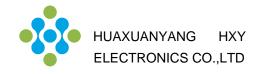
Package Information TO-220C-2L



0/4/001	[NOTEO		
SYMBOL	MIN.	NOM.	MAX.	NOTES
А	4,24	4,44	4.64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
b	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.45	1.70	
с	0.40	0.50	0.60	
D	14.70	15.37	16.00	4
D1	8,82	8,92	9.02	
D2	12.43	12.73	12.83	5
E	9.96	10.16	10.36	4,5
E1	6,86	7.77	8,89	5
E3*				
е				
e1	5.08BSC			
H1	6.30	6.45	6.60	5,6
L	13.47	13.72	13.97	
L1	3.60	3.80	4.00	
ØP	3,75	3.84	3,93	
Q	2,60	2,80	3,00	
Q1*				
R*				

Recommended Solder Pad Layout





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